



# TF2003M

## Half-Bridge Gate Driver

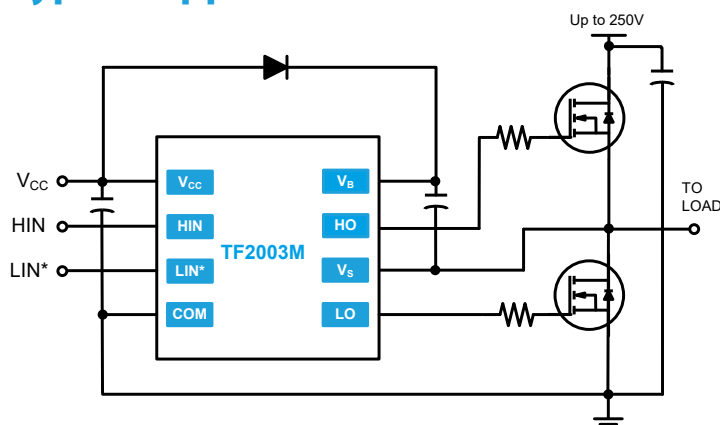
### Features

- Floating high-side driver in bootstrap operation to 250V
- Drives two N-channel MOSFETs or IGBTs in a half bridge configuration
- Designed for enhanced performance in noisy motor applications
- 290mA source/600mA sink output current capability
- Outputs tolerant to negative transients
- Internal dead time of 420ns to protect MOSFETs
- Wide low side gate driver supply voltage: 10V to 20V
- Logic input (HIN and LIN\*) 3.3V capability
- Schmitt triggered logic inputs
- Undervoltage lockout for  $V_{CC}$  (logic and low side supply)
- Extended temperature range: -40°C to +125°C

### Applications

- Motor Controls
- DC-DC Converters
- AC-DC Inverters
- Motor Drives

### Typical Application



### Description

The TF2003M is a high voltage, high speed gate driver capable of driving N-channel MOSFETs and IGBTs in a half bridge configuration. TF Semiconductors's high voltage process enables the TF2003M high side to switch to 250V in a bootstrap operation.

The TF2003M logic inputs are compatible with standard TTL and CMOS levels (down to 3.3V) to interface easily with controlling devices. The driver outputs feature high pulse current buffers designed for minimum driver cross conduction. TF2003M has a fixed internal deadtime of 420ns (typical).

The TF2003M is offered in a SOIC-8(N) and PDIP-8 package and operates over an extended -40 °C to +125 °C temperature range.



SOIC-8(N)



PDIP-8

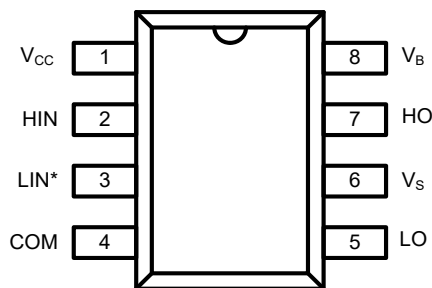
### Ordering Information

Year Year Week Week

PART NUMBER	PACKAGE	PACK / Qty	MARK
TF2003M-3AS	PDIP-8	Tube / 50	YYWW TF TF2003M Lot ID
TF2003M-TAU	SOIC-8(N)	Tube / 100	YYWW TF TF2003M Lot ID
TF2003M-TAH	SOIC-8(N)	T&R / 2500	YYWW TF TF2003M Lot ID



**Pin Diagrams**



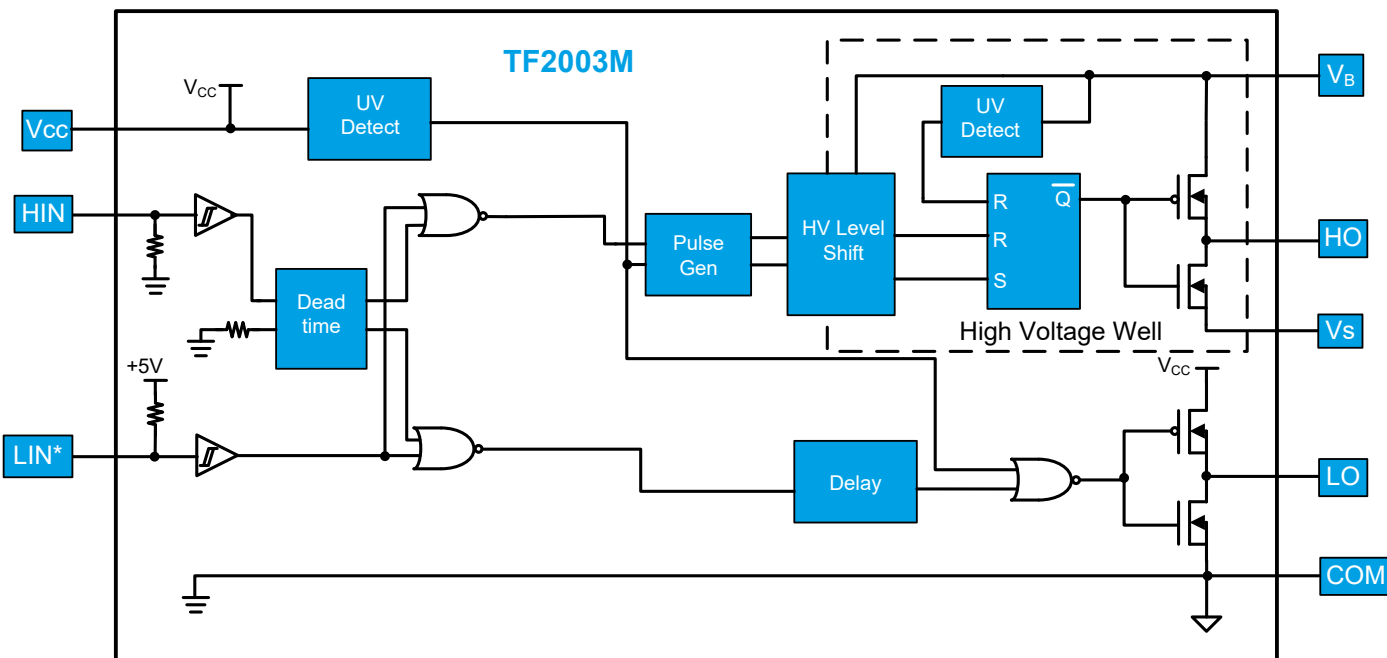
**Top View: SOIC-8**

**TF2003M**

**Pin Descriptions**

PIN NAME	PIN NUMBER	PIN DESCRIPTION
V <sub>CC</sub>	1	Logic and low side supply
HIN	2	Logic input for high-side gate driver output in phase with HO
LIN*	3	Logic input for low-side gate driver output out of phase with LO
COM	4	Low-side and logic return
LO	5	Low-side gate drive output
V <sub>S</sub>	6	High-side floating supply return
HO	7	High-side gate drive output
V <sub>B</sub>	8	High-side floating supply

**Functional Block Diagram**





## Absolute Maximum Ratings (NOTE1)

$V_B$  - High side floating supply voltage.....-0.3V to +274V  
 $V_S$  - High side floating supply offset voltage... $V_B$ -24V to  $V_B$ +0.3V  
 $V_{HO}$  - High side floating output voltage..... $V_S$ -0.3V to  $V_B$ +0.3V  
 $dV_S/dt$  - Offset supply voltage transient.....50 V/ns

$V_{CC}$  - Low-side fixed supply voltage.....-0.3V to +24V  
 $V_{LO}$  - Low-side output voltage.....-0.3V to  $V_{CC}$ +0.3V  
 $V_{IN}$  - Logic input voltage (HIN and LIN\*).....-0.3V to  $V_{CC}$ +0.3V

**NOTE1** Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

$P_D$  - Package power dissipation at  $T_A \leq 25^\circ\text{C}$   
 SOIC-8.....0.625W

SOIC-8(N) Thermal Resistance (**NOTE2**)

$\theta_{JA}$ .....200  $^\circ\text{C}/\text{W}$

$T_J$  - Junction operating temperature.....+150  $^\circ\text{C}$

$T_L$  - Lead Temperature (soldering, 10 seconds).....+300  $^\circ\text{C}$

$T_{stg}$  - Storage temperature .....-55 to 150  $^\circ\text{C}$

**NOTE2** When mounted on a standard JEDEC 2-layer FR-4 board.

## Recommended Operating Conditions

Symbol	Parameter	MIN	MAX	Unit
$V_B$	High side floating supply absolute voltage	$V_S + 10$	$V_S + 20$	V
$V_S$	High side floating supply offset voltage	<b>NOTE3</b>	250	V
$V_{HO}$	High side floating output voltage	$V_S$	$V_B$	V
$V_{CC}$	Low side fixed supply voltage	10	20	V
$V_{LO}$	Low side output voltage	0	$V_{CC}$	V
$V_{IN}$	Logic input voltage (HIN and LIN*)	0	5	V
$T_A$	Ambient temperature	-40	125	$^\circ\text{C}$

**NOTE3** Logic operational for  $V_S$  of -5V to +250V.



## DC Electrical Characteristics *(NOTE4)*

$V_{BIAS} (V_{CC}, V_{BS}) = 15V, T_A = 25^\circ C$ , unless otherwise specified.

Symbol	Parameter	Conditions	MIN	TYP	MAX	Unit
$V_{IH}$	Logic "1" (HIN) & Logic "0" (LIN*) input voltage	$V_{CC} = 10V$ to $20V$	2.5			V
$V_{IL}$	Logic "0" (HIN) & Logic "1" (LIN*) input voltage				0.8	
$V_{OH}$	High level output voltage, $V_{BIAS} - V_O$	$I_O = 2mA$		0.05	0.2	
$V_{OL}$	Low level output voltage, $V_O$	$I_O = 2mA$		0.02	0.1	
$I_{LK}$	Offset supply leakage current	$V_B = V_S = 250V$			50	$\mu A$
$I_{BSQ}$	Quiescent $V_{BS}$ supply current	$V_{IN} = 0V$ or $5V$		60	100	
$I_{CCQ}$	Quiescent $V_{CC}$ supply current	$V_{IN} = 0V$ or $5V$		350	500	
$I_{IN+}$	Logic "1" input bias current	$HIN = 5V, LIN^* = 0V$		3	10	
$I_{IN-}$	Logic "0" input bias current	$HIN = 0V, LIN^* = 5V$			5	
$V_{CCUV+}$	$V_{CC}$ supply under-voltage positive going threshold		8.0	8.9	9.8	V
$V_{CCUV-}$	$V_{CC}$ supply under-voltage negative going threshold		7.4	8.2	9.0	
$V_{BSUV+}$	$V_{BS}$ supply under-voltage positive going threshold		4.5	5.5	6.5	V
$V_{BSUV-}$	$V_{BS}$ supply under-voltage negative going threshold		4.2	5.2	6.2	V
$I_{O+}$	Output high short circuit pulsed current	$V_O = 0V, PW \leq 10 \mu s$	130	290		mA
$I_{O-}$	Output low short circuit pulsed current	$V_O = 15V, PW \leq 10 \mu s$	270	600		

**NOTE4** The  $V_{IH}$ ,  $V_{IL}$ , and  $I_{IN}$  parameters are applicable to the two logic input pins: HIN and LIN\*. The  $V_O$  and  $I_O$  parameters are applicable to the respective output pins: HO and LO



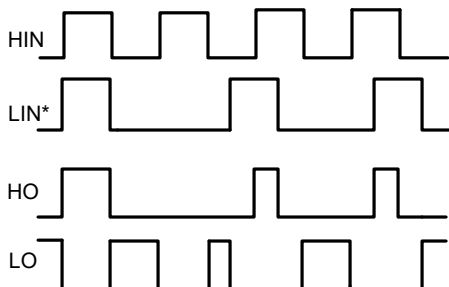
## AC Electrical Characteristics

$V_{BIAS} (V_{CC}, V_{BS}) = 15V$ ,  $C_L = 1000pF$ , and  $T_A = 25^\circ C$ , unless otherwise specified.

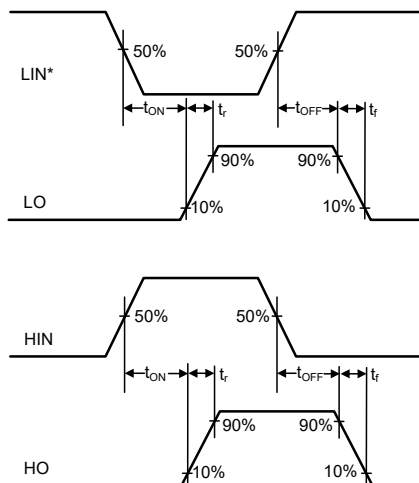
Symbol	Parameter	Conditions	MIN	TYP	MAX	Unit
$t_{on}$	Turn-on propagation delay	$V_S = 0V$		680	820	ns
$t_{off}$	Turn-off propagation delay	$V_S = 250V$		150	220	
$t_{DM}$	Delay matching, HS & LS turn-on/turn-off				60	
$t_r$	Turn-on rise time	$V_S = 0V$		70	170	
$t_f$	Turn-off fall time			35	90	
$t_{DT}$	Deadtime: $t_{DT LO-HO}$ & $t_{DT HO-LO}$		300	420	650	



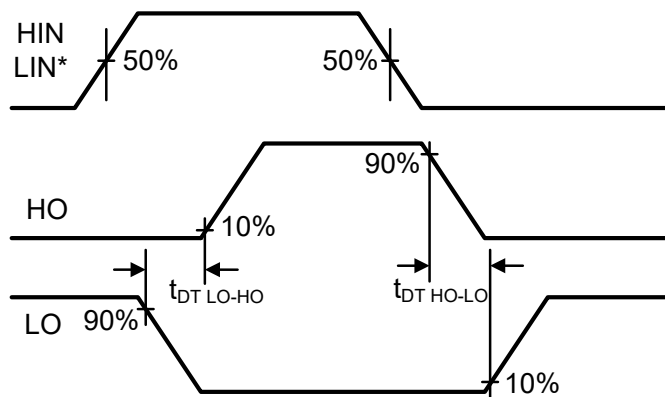
# Timing Waveforms



**Figure 1.** Input / Output Timing Diagram



**Figure 2.** Switching Time Waveform Definitions

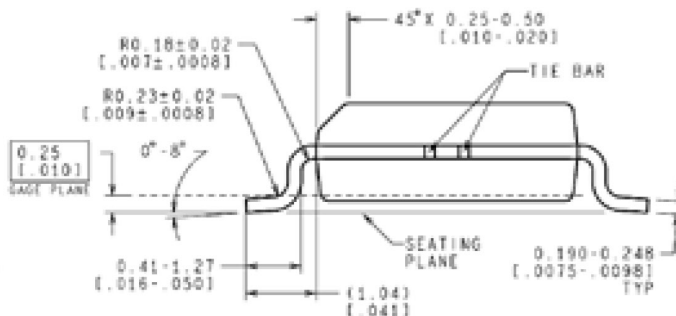
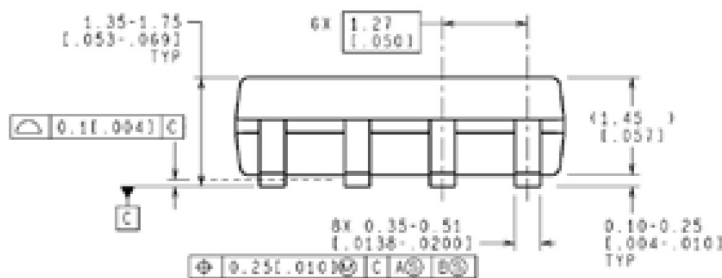
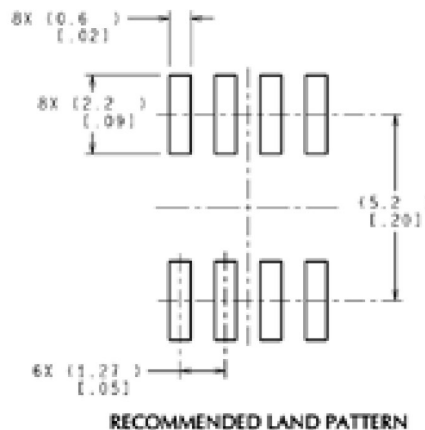
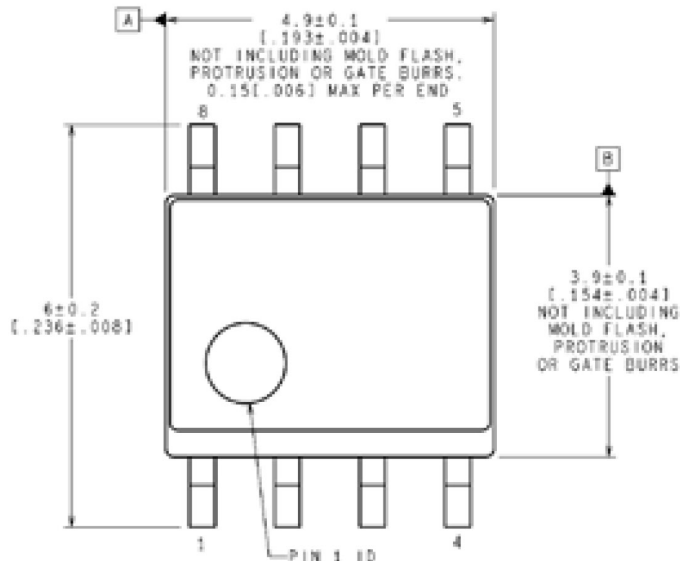


**Figure 3.** Deadtime Waveform Definitions



## Package Dimensions (SOIC-8 N)

Please contact support@telefunkensemi.com for package availability.



NOTES: UNLESS OTHERWISE SPECIFIED

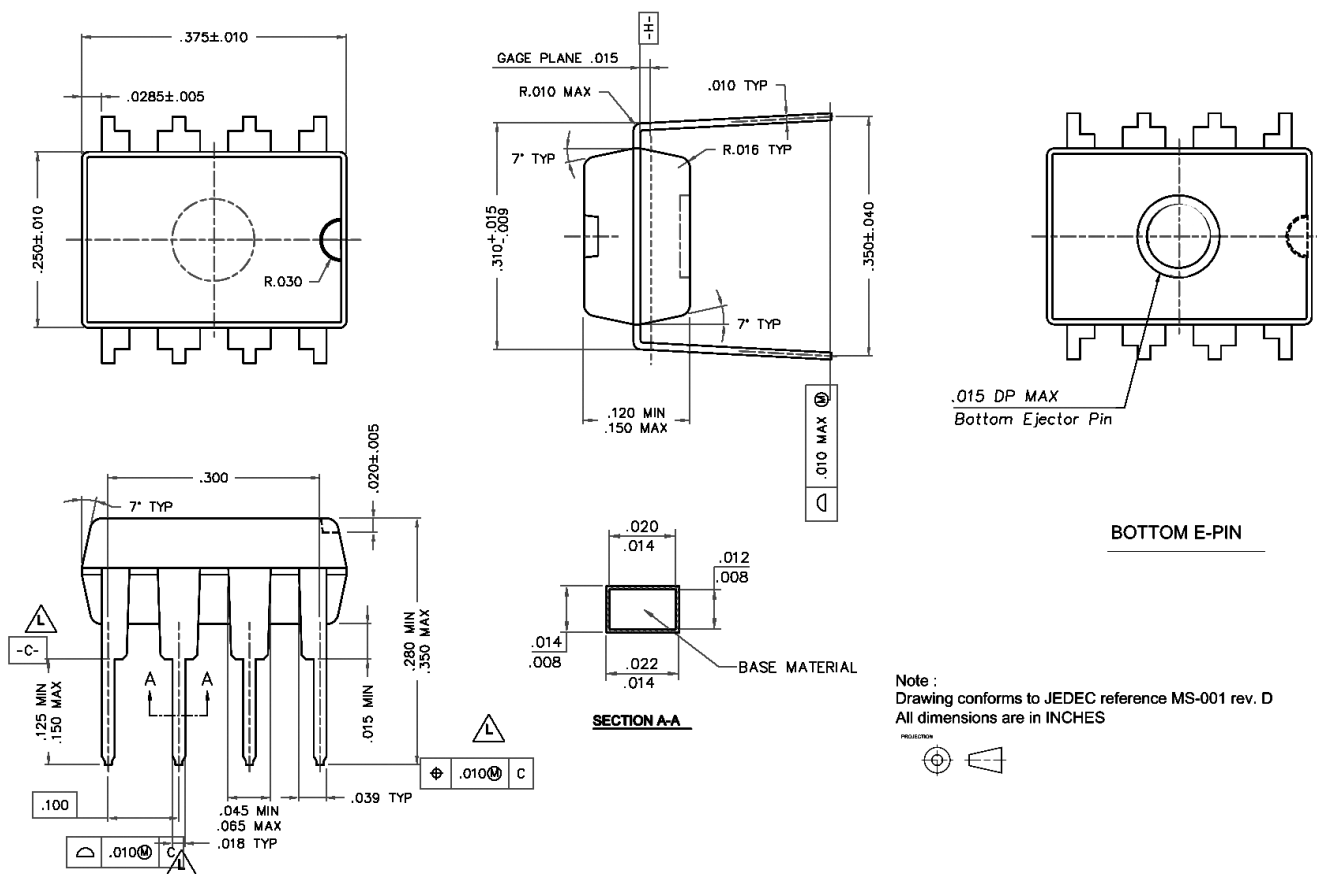
1. REFERENCE JEDEC REGISTRATION MS-012, VARIATION AA.

CONTROLLING DIMENSION IS MILLIMETER  
VALUES IN [ ] ARE INCHES  
DIMENSIONS IN ( ) FOR REFERENCE ONLY



## Package Dimensions (PDIP-8)

Please contact support@tfsemi.com for package availability.







## Revision History

Rev.	Change	Owner	Date
1.0	First release, AI datasheet	Keith Spaulding	2/1/2018

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